

**Flexoelectret: An Electret with a Tunable Flexoelectriclike Response**Xin Wen,<sup>1,‡</sup> Dongfan Li,<sup>2,‡</sup> Kai Tan,<sup>1</sup> Qian Deng,<sup>1,\*</sup> and Shengping Shen<sup>1,†</sup><sup>1</sup>*State Key Laboratory for Strength and Vibration of Mechanical Structures, School of Aerospace Engineering, Xi'an Jiaotong University, Xi'an 710049, China*<sup>2</sup>*Frontier Institute of Science and Technology, State Key Laboratory of Electrical Insulation and Power Equipment, Xi'an Jiaotong University, Xi'an 710054, China*

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Because of the flexoelectric effect, dielectric materials usually polarize in response to a strain gradient. Soft materials are good candidates for developing a large strain gradient because of their good deformability. However, they always suffer from lower flexoelectric coefficients compared to ceramics. In this work, a flexoelectriclike effect is introduced to enhance the effective flexoelectricity of a polydimethylsiloxane bar. The flexoelectriclike effect is realized by depositing a layer of net charges on the middle plane of the bar to form an electret. Experiments show that the enhancement of flexoelectricity depends on the density of inserted net charges. It is found that a charged layer with surface potential of  $-5723$  V results in a 100 times increase of the material's flexoelectric coefficient. We also show that the enhancement is proportional to the thickness of electrets. This work provides a new way of enhancing flexoelectricity in soft materials and further prompts the application of soft materials in electromechanical transducers.

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Flexoelectricity is a widely observed property of dielectric materials (including crystals [1,2], polymers [3], biomembranes [4,5], bones [6], liquid crystals [7], semiconductors [8], etc.), which couples the strain gradient and the electric polarization. When a dielectric material is deformed nonuniformly, regardless of its initial crystalline symmetry, the strain gradient would break or change its spatial inversion symmetry and consequently induce a change of the polarization [9–11]. In materials showing flexoelectricity, the ratio of the change of polarization to the strain gradient is defined as the flexoelectric coefficient. Since the strain gradient scales up with the decrease of the sample size, large strain gradients are usually found at small length scales. For this reason, several applications and/or ramifications of flexoelectricity at the nanoscale have been reported recently [12–21]. However, a macroscopic strain gradient is usually too small to produce relatively strong polarization unless the material has a very large flexoelectric coefficient [22–25].

To obtain large strain gradient at the macroscopic scale, a possible way is to use soft materials which are able to endure large strain before failure. So, it is interesting to study flexoelectricity in polymers with much better deformability than ceramics [26,27]. Other reasons for studying flexoelectricity in polymers lie in the fact that they are biocompatible, environmentally friendly, and suitable for applications in stretchable electronics. However, one of the biggest issues for flexoelectric polymers is their small flexoelectric coefficients. Chu and Salem have measured the flexoelectric coefficient for polymers to be  $10^{-9} - 10^{-8}$  C m<sup>-1</sup> [3] which

is several orders of magnitude smaller than that for ferroelectric materials reported by Ma and Cross ( $\sim 10^{-6}$  C m<sup>-1</sup>) [22,23]. Thus, in addition to the introduction of large strain, it is necessary to further enhance the flexoelectric coefficient of polymers in order to achieve a strong flexoelectric effect.

In this work, other than increasing the intrinsic flexoelectric coefficient, we introduce a flexoelectriclike effect in electret materials. An electret is a dielectric material that contains quasipermanent electrical charges. A well-known example for the application of electret materials is the ferroelectret (or piezoelectret), a cellular polymer film with charged air bubbles. Each charged air bubble may be viewed as a capacitor. When the material is deformed, the shape of air bubbles changes accordingly. In this way, the overall capacitance and polarization of the material are changed with its deformation. In other words, the material exhibits effective piezoelectricity. The strength of this effective piezoelectricity is found to be several tens of times greater than that of the most used piezoelectric polymer, poly(vinylidene fluoride) (PVDF) [28,29]. In recent years, ferroelectret has shown great potential in multiple areas such as energy harvesting [30,31], sensing [32,33], and self-powered electronics [34,35], due to its high flexibility and effective piezoelectricity.

Motivated by ferroelectrets, here we propose a new design, flexoelectret, which shows effective flexoelectricity upon the application of nonuniform deformation. The structure of a flexoelectret is schematically drawn in Fig. 1(a). As shown in the figure, a layer of spatial charges is placed on the middle plane of a polydimethylsiloxane

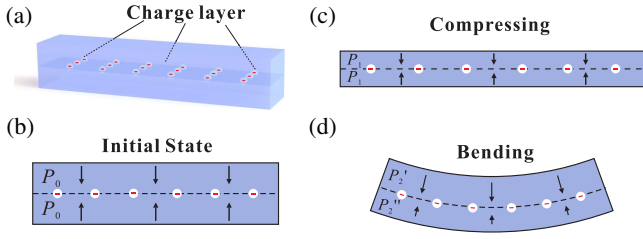


FIG. 1. Schematic illustration of the mechanism of the flexoelectret. Arrows in this figure represent polarization. Longer arrows correspond to larger polarization. (a) Structure of the flexoelectret. A layer of charges is deposited on the middle plane of a PDMS bar. (b) Initial state of the flexoelectret. The polarizations above and below the charge layer have the same magnitude  $P_0$  but opposite directions. (c) Under uniform compression, the shape of the bar has changed but is still symmetric about the middle plane. The polarizations of two parts still have the same magnitude  $P_1$  and opposite directions. (d) Under bending the symmetry of the bar is broken. The magnitudes of polarization  $P'_2$  and  $P''_2$  are no longer the same, which generates net polarization along the thickness direction.

(PDMS) bar. The reason we choose PDMS instead of the commonly used flexoelectric polymer PVDF is that PDMS is much more deformable compared to PVDF. Larger deformation is helpful for creating a large strain gradient, and thus positive to the flexoelectric effect. Because of the charge layer placed on the middle plane of the PDMS bar, the material is polarized and the induced polarizations above and below the charge layer have exactly the same magnitude  $P_0$  but opposite directions [Fig. 1(b)]. Thus, the overall polarization of the charged PDMS bar is zero. If we apply a uniform tension or compression to the bar, as shown in Fig. 1(c), its thickness and length would change in response to the mechanical loading. Consequently, the polarization would also change from  $P_0$  to  $P_1$ . At this time, since the uniform deformation does not break the symmetry of the bar about its middle plane, the overall polarization is still zero. In other words, this charged PDMS bar shows no effective piezoelectricity. Actually, shifting the charge layer away from the middle plane does not contribute to the effective piezoelectricity since uniform deformation cannot change the net polarization of the sample. This point can be verified by Kacprzyk's theoretical work in which the effective piezoelectric coefficient of an electret is given by [36]

$$d_{33}^{\text{eff}} = -q_0 \frac{\varepsilon_1 \varepsilon_2 h_1 h_2}{(\varepsilon_1 h_1 + \varepsilon_2 h_2)} \left( \frac{1}{Y_2} - \frac{1}{Y_1} \right) \quad (1)$$

where  $q_0$  is the density of the charge layer,  $\varepsilon_1$  and  $\varepsilon_2$ , respectively, correspond to the permittivity value of the materials below and above the charge layer,  $h_1$  and  $h_2$  are the distance from the charge layer to the lower and upper surfaces of the bar, and  $Y_1$ ,  $Y_2$  denote the Young's modulus of the materials below and above the charge layer, respectively. This formula predicts the effective piezoelectricity of

a double layered sample under uniform compression or tension. It is seen from the formula that the materials above and below the charge layer need to be different in order to produce nonzero effective piezoelectricity. For the model shown in Fig. 1(a), obviously  $Y_1$  is equal to  $Y_2$ . So, the effective piezoelectric coefficient  $d_{33}^{\text{eff}}$  vanishes no matter whether  $h_1$  is equal to  $h_2$  or not.

While if subjected to a nonuniform loading, for example, a bending moment, the PDMS bar shown in Fig. 1(a) would no longer keep its symmetry. The upper and lower parts of the sample would experience totally different deformations. Upon a pure bending, the lower layer would expand while the upper layer would shrink. Thus, the strain across the thickness direction is nonuniform. Figure 1(d) shows that, because of this biased deformation, the magnitudes of polarization  $P'_2$  and  $P''_2$ , which, respectively, correspond to the polarization above and below the charge layer, may not cancel each other and there are net polarizations developed in the sample. Further bending would enhance the difference between the deformations of the upper and lower surfaces. Thus, the net polarization increases with the degree of the bending. For such flexoelectriclike phenomenon, we define the ratio between the net polarization along the thickness direction and the curvature of the middle plane of the PDMS bar as the effective flexoelectric coefficient  $\mu_{13}^{\text{eff}}$ . To analytically derive the expression for  $\mu_{13}^{\text{eff}}$ , we account for the finite deformation (or large deformation) of the bar and have the following equation (see the Supplemental Material [37])

$$\mu_{13}^{\text{eff}} = \frac{q \ln(1 + \kappa H) + \ln(1 - \kappa H)}{2\kappa \ln(1 + \kappa H) - \ln(1 - \kappa H)}, \quad (2)$$

where  $q$  and  $\kappa$ , respectively, correspond to the charge density and curvature of the middle plane and  $H$  is the thickness of the bar. If  $\kappa H \ll 1$ ,  $\mu_{13}^{\text{eff}}$  can be further reduced to the following form:

$$\mu_{13}^{\text{eff}} \approx -\frac{Hq}{4}. \quad (3)$$

The simplified form is similar to Ref. [38]. It is also similar in form to Ref. [39], in which piezoelectric coefficient is inhomogeneously and asymmetrically across the sample.

It is worthwhile to mention that such bending-induced redistribution of polarization commonly exists in lipid bilayer membranes and is proposed to be the mechanism of the flexoelectricity of biomembranes [4,40–42]. The lipid bilayer consists of two layers of lipid molecules which are arranged in such a way that their hydrophilic heads are pointing outside and in contact with the environment while hydrophobic tails are pointing inside and isolated. As shown in Fig. 2(a), there are initial polarizations in the biomembrane. If the membrane is flat and the environment

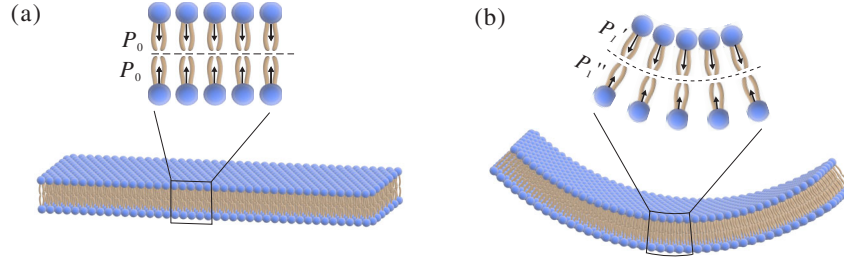


FIG. 2. Structure of a lipid bilayer membrane. Arrows represent the average polarization of the lipid molecules. Longer arrows correspond to larger polarization. (a) A flat lipid bilayer membrane, which is symmetric about its middle plane. (b) A curved lipid bilayer membrane. The symmetry of membrane is broken, which leads to net polarization.

on both sides is the same, there is no net polarization because the bilayer is symmetric about its middle plane. While, as we can see from Fig. 2(b), bending the membrane would break this symmetry and induce net polarization which is proportional to the membrane's curvature. In reality, no lipid bilayer is absolutely flat and there are also protein molecules embedded in the biomembrane. Thus, initially, the system is not symmetric and there are net polarizations. Further bending the membrane would change the degree of the asymmetry and thus lead to a further change of its net polarization.

To experimentally proof the existence of such flexoelectriclike phenomenon, we choose three-point bending experiments here. Since all dielectric materials show flexoelectricity, we first performed a three-point bending test on pure PDMS without net charges to check how the material's intrinsic flexoelectricity would affect its electro-mechanical behavior. Figure 3(a) shows the experimental setup for flexoelectric measurement. The test sample is a PDMS bar with the size of  $100 \text{ mm} \times 15 \text{ mm} \times 10 \text{ mm}$  and coated with compliant electrodes (liquid metal) on its upper and lower surfaces. A load machine applied a sinusoidal oscillatory force at a frequency of 1 Hz to the center point of the bar's upper surface. Two supporting edges were separated by  $L = 80 \text{ mm}$ . The vertical displacement of the center point of the bar's upper surface  $\delta$  was recorded (peak value was equal to 1.5 mm). The bending-induced polarization charges  $Q$  were detected

using a charge amplifier and an oscilloscope. Then the intrinsic transverse flexoelectric coefficient  $\mu_{13}$  can be calculated according to

$$\bar{P}_3 = \mu_{13} \frac{\partial \varepsilon_{11}}{\partial x_3} \quad (4)$$

and

$$\bar{P}_3 = \frac{Q}{A} \quad (5)$$

where  $A$  is the area of the electrode, and  $\frac{\partial \varepsilon_{11}}{\partial x_3}$  is the average strain gradient across the thickness direction, which can be calculated by the finite element method (FEM) based on measured  $L$  and  $\delta$  (see the Supplemental Material [37]). In order to eliminate electromagnetic interferences from the environment, we filtered the data and extracted the signal at 1 Hz. In Fig. 3(b), the red dashed line and blue solid line depict the variation of charge output  $Q$  and vertical displacement  $\delta$  for the case of a pure PDMS bar. We found through calculations that the intrinsic flexoelectric coefficient  $\mu_{13}$  of PDMS is  $5.3 \times 10^{-10} \text{ Cm}^{-1}$ , much lower than the measured value for PVDF ( $\sim 10^{-8} \text{ Cm}^{-1}$ ).

Then we made a flexoelectret by placing a piece of charged thin film with the density of  $q_0$  on the middle plane of the PDMS bar (see the Supplemental Material [37]) and repeated the above-mentioned three-point bending test.

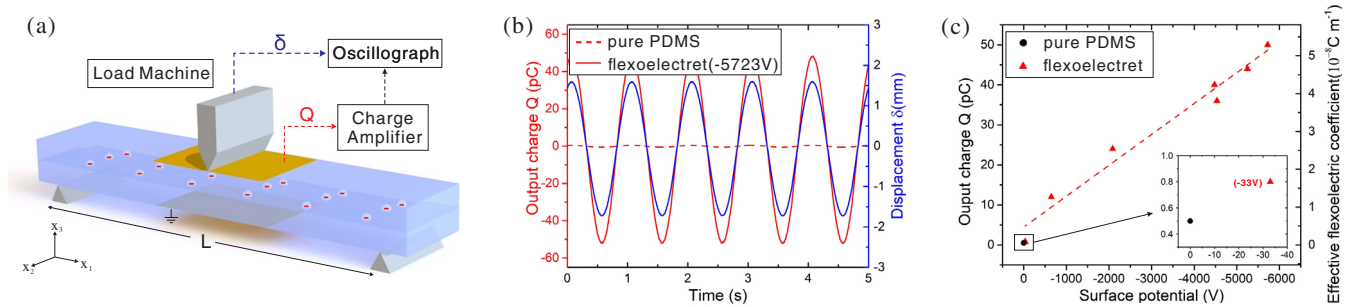


FIG. 3. Experimental setup and results. (a) Experimental setup for flexoelectric measurement. (b) Output charge  $Q$  from the upper electrode and vertical displacement of the center point of the sample, corresponding to the red and blue lines, respectively. (c) Output charge  $Q$  and the effective flexoelectric coefficient  $\mu_{13}^{\text{eff}}$  as a function of the surface potential of the charge layer. The inset shows output charge of pure PDMS and flexoelectret ( $-33 \text{ V}$ ).

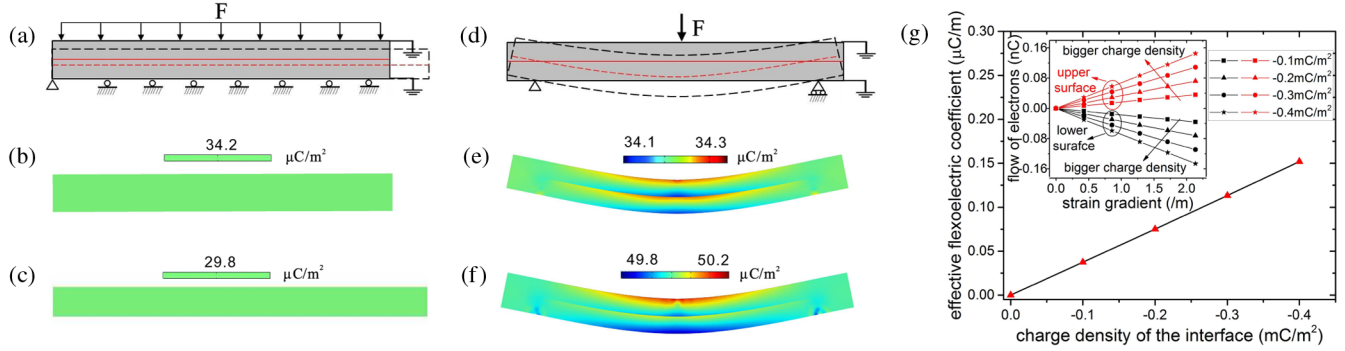


FIG. 4. Schematic illustration of the FEM model of flexoelectrets and calculated results. The polarization and electric displacement distribution are all absolute values. Dashed lines represent the deformed model. (a) Model under uniform pressure. (b) Preexisting polarization distribution in the initial state, which is uniform. (c) Polarization distribution under uniform compression, which is still uniform. (d) Model under three-pointing bending. (e),(f) Polarization and electric displacement distribution under bending, respectively, showing a strong asymmetry. (g) Calculated effective flexoelectric coefficient as a function of charge density. The inset shows the dependence of the electronic flow on the strain gradient and charge density.

Note that measuring charge density directly is difficult. So, we use surface potential to characterize the charge density of the charged film. The larger surface potential corresponds to larger charge density and these two quantities have a roughly linear relationship to each other [36]. The experimental result is also given by Fig. 3(b). In Fig. 3(b), the red solid line depicts the variation of the output charge  $Q$  with respect to time in response to the same displacement  $\delta$  as shown by the blue solid line. Comparing the red dashed line and the red solid line in Fig. 3(b), we found a strong enhancement of the electromechanical coupling of the flexoelectret over pure PDMS. Following exactly the same process for calculating the intrinsic flexoelectric coefficient above, we measured the effective flexoelectric coefficient of the flexoelectret  $\mu_{13}^{\text{eff}}$  to be  $5.3 \times 10^{-8} \text{ C m}^{-1}$  when the surface potential of the charged film is  $-5723 \text{ V}$ . This value is 2 orders of magnitude higher than that of pure PDMS. Although this flexoelectric coefficient is at the same order of magnitude as that for PVDF, much larger deformability of PDMS over PVDF allows a more significant flexoelectric effect in the former if testing at the same length scale. Note that this effective flexoelectricity is caused neither by the noncentrosymmetric distortion of the microstructure (the origination of intrinsic flexoelectricity) nor by the uniform change of the capacitance (the origination of piezoelectret effect). The flexoelectriclike effect observed here stems from the redistribution of preexisting polarizations under nonuniform deformation. Note that the preexisting polarization mentioned here is caused by the net charges placed on the middle plane. If there is no preexisting polarization, the flexoelectriclike effect would vanish. We propose here that larger preexisting polarization should lead to a stronger flexoelectriclike effect. To confirm this point, the same three-point bending test was conducted on electrets with different densities of charges on the middle plane. It is found from Fig. 3(c) that

the output charge increases almost linearly with respect to the charge density of the middle plane. When the surface potential is reduced to  $-33 \text{ V}$ , the output charge is almost the same as that for the case of pure PDMS. This linear dependency of the effective flexoelectric coefficient on the charge density (or surface potential measured on the charged PTFE thin film) is consistent with Eq. (3).

We also simulated the phenomenon using FEM (COMSOL MULTIPHYSICS 5.2). Figure 4(a) illustrates the schematic diagram of the established model with the same size and material parameters as the experimental specimen (see the Supplemental Material [37]). The red solid line represents a layer of charge embedded in the interface between two layers of the same dielectric material. Note that the polarization and electric displacement fields above and below the interface have opposite directions; to accurately distinguish the difference between their magnitudes, we plotted absolute value of the polarization and electric displacement in Figs. 4(b), 4(c), 4(e), and 4(f). Figure 4(b) shows that the preexisting polarization distribution is uniform, which means the overall polarization is zero. When subjected to uniform pressure, as shown in Fig. 4(c), the overall polarization is still zero. This is because the symmetry of the model has not been broken by the uniform strain.

Then we bent the bar by applying concentric force  $F$  to the middle point of its upper boundary and fixing its lower left and lower right ends [Fig. 4(d)]. Figures 4(e) and 4(f) show the redistribution of polarization and electric displacement, respectively. It can be seen clearly that the symmetry of the model was broken due to the bending deformation. Figure 4(g) (inset) shows the electrons flowing from the lower surface to the upper surface (see the Supplemental Material [37]). Obviously, further bending the sample and larger charge density both lead to more charges flow. Then we obtained the effective flexoelectric



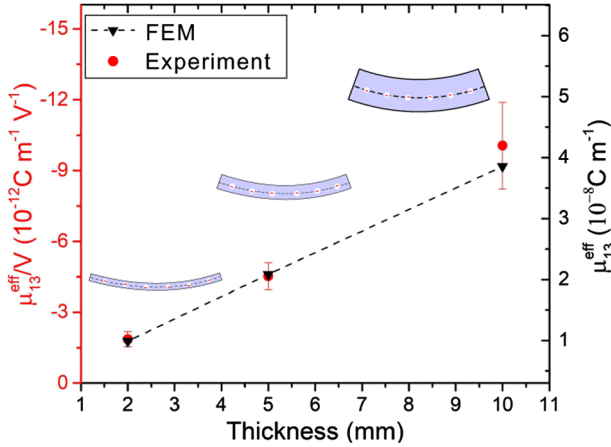


FIG. 5. Normalized effective flexoelectricity as a function of sample thickness. The results show a linear relationship between flexoelectricity and thickness.

coefficient  $\mu_{13}^{\text{eff}}$  using Eqs. (4) and (5). Again, from Fig. 4(g), linear dependency of  $\mu_{13}^{\text{eff}}$  on the charge density is also observed.

Equation (3) also predicts that  $\mu_{13}^{\text{eff}}$  is proportional to  $H$ . Thus, in Fig. 5, we investigate the effect of the sample thickness on the effective flexoelectric coefficient. We used specimens with different thickness (2, 5, and 10 mm) but the same length and width for flexoelectric testing. Since it is difficult to control the surface potential  $V$  (or equivalently charge density) on a PTFE thin film accurately, to eliminate the influence of different surface potential and only investigate the impact from the thickness change, we divide the measured coefficients  $\mu_{13}^{\text{eff}}$  by  $V$ . Figure 5 shows that the normalized effective flexoelectricity is proportional to sample thickness. FEM simulation results (charge density is set to be  $-0.1 \text{ mC m}^{-2}$ ) shown in Fig. 5 also indicate that  $\mu_{13}^{\text{eff}}$  increases linearly with respect to the sample thickness. Interestingly, Abdollahi and his collaborators also found that the effective flexoelectric coefficient is proportional to the thickness of the sample in their recent work [39].

The strength of the flexoelectric effect in materials depends on their flexoelectric coefficients as well as the strain gradient that can be developed in them. In this work, large strain gradients are realized through the use of highly deformable materials and, at the same time, the flexoelectric coefficient is enhanced by an electret based flexoelectriclike phenomenon which stems from the interaction between nonuniform deformations and the initial polarization field. Specifically, a PDMS bar is used for the flexoelectret, and the initial polarization field is introduced by a layer of net charge deposited in its middle plane. Experiments indicate that this charged PDMS bar has an effective flexoelectric coefficient which is 100 times of its intrinsic flexoelectric coefficient. It is also found both theoretically and experimentally that the effective flexoelectric coefficient  $\mu_{13}^{\text{eff}}$  of this flexoelectret linearly depends

on both the sample thickness and the density of net charges deposited on its middle plane. This work provides an example of the interaction between nonuniform deformations and the polarization field, introduces a new way of enhancing flexoelectric coefficients in soft materials, and also shows a novel application of electrets. Since current flexoelectric energy harvesting is usually based on nano-beams with extremely high resonant frequencies, the flexoelectret introduced here may have promising applications in low frequency flexoelectric energy harvesting.

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